

Technical Data

DIODE



maximum ratings

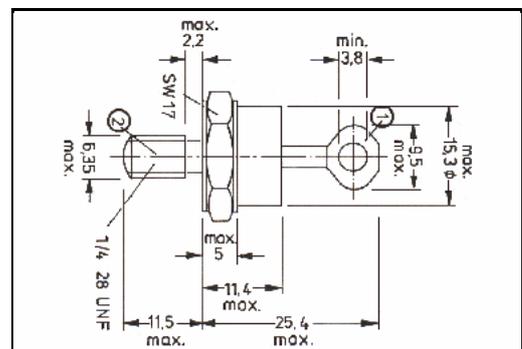
Voltage, Reverse (VR)	600.0	V	NO.	1N1190R
Voltage, Reverse Peak (VRM)	600.0	V	TYPE	SI - RECTIFIER
Current at VR = 0V (IO)		A		
Current Average Rectified (IF)	40.0	A		
Current Surge Peak (IFM)		A	CASE	DO-5_UNF
Current, Surge (IFM) at tp = 8.3 ms	500.0	A		ANODE-TO-CASE
Max. Power Dissipation (PT) at TC = 25 °C		W		
Max. Thermal Resistance (Rth J-C)	0.9	°C/W		
Max. Junction Temperature (TJ)	200.0	°C		

PERFORMANCE CHARACTERISTICS at $T_c = 25^\circ\text{C}$, unless otherwise noted

NO.	SYMBOL	CONDITIONS	MIN.	MAX.	UNITS
1.	VF	IF = 100.0 A (1)	-	1.3	V
2.	IR	VR = 600.0 V	-	30.0	μA
3.	IR	VR = 600.0 V, TC = 150.0° C	-	3.0	mA
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Notes (1)pulse-tested $t_p \leq 300 \mu\text{s}$, duty cycle $\leq 2\%$

DIMENSIONS in mm



Marking 1N1190R
 Customer GENERAL PURPOSE